# **74LVC646A**

# Octal bus transceiver/register; 3-state

Rev. 5 — 28 March 2013

**Product data sheet** 

## 1. General description

The 74LVC646A consists of non-inverting bus transceiver circuits with 3-state outputs, D-type flip-flops and control circuitry arranged for multiplexed transmission of data directly from the internal registers. Data on the A or B bus is clocked in the internal registers, as the appropriate clock (CPAB or CPBA) goes to a HIGH logic level. Output enable ( $\overline{OE}$ ) and direction (DIR) inputs are provided to control the transceiver function. In the transceiver mode, data present at the high-impedance port may be stored in either the A or B register, or in both. With the select source inputs (SAB and SBA), stored and real-time (transparent mode) data can be multiplexed. The direction (DIR) input determines which bus receives data when  $\overline{OE}$  is active (LOW). In the isolation mode ( $\overline{OE}$  = HIGH), A data may be stored in the B register and/or B data may be stored in the A register. When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses A or B may be driven at a time.

Inputs can be driven from either 3.3~V or 5~V devices. When disabled, up to 5.5~V can be applied to the outputs. These features allow the use of these devices as translators in mixed 3.3~V and 5~V applications.

### 2. Features and benefits

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Supply voltage range from 1.2 V to 3.6 V
- CMOS low-power consumption
- Direct interface with TTL levels
- 8-bit octal transceiver with D-type latch
- Back-to-back registers for storage
- Separate controls for data flow in each direction
- Supports partial power-down applications; inputs/outputs are high-impedance when V<sub>CC</sub> = 0 V
- Complies with JEDEC standard:
  - ◆ JESD8-7A (1.65 V to 1.95 V)
  - ◆ JESD8-5A (2.3 V to 2.7 V)
  - ◆ JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-B exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.



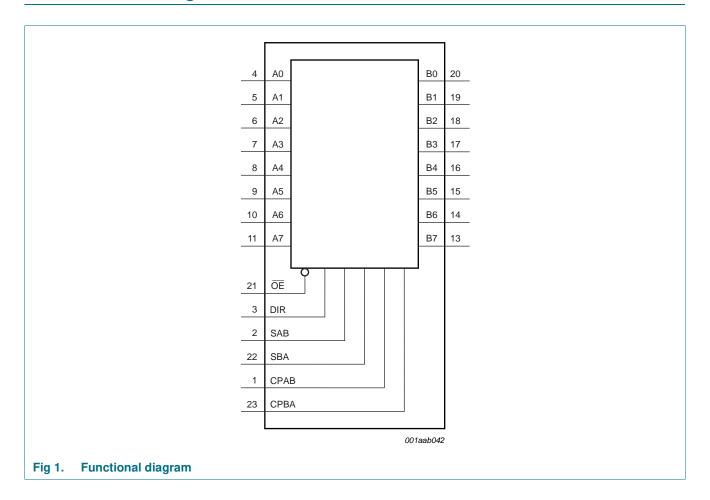
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# 3. Ordering information

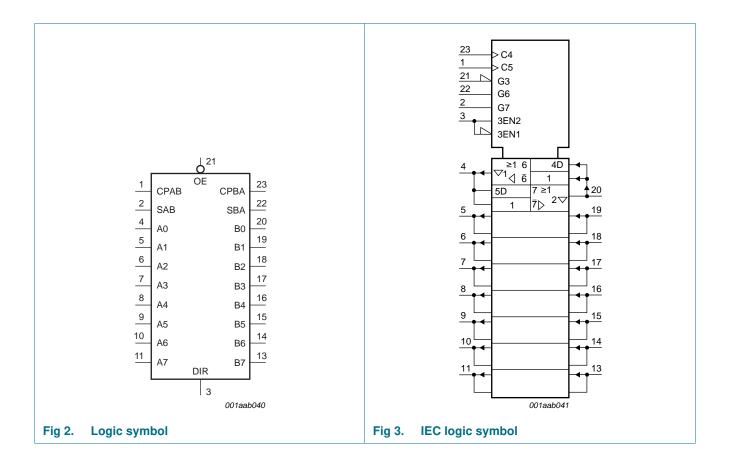
Table 1. Ordering information

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74LVC646AD	–40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1						
74LVC646ADB	–40 °C to +125 °C	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1						
74LVC646APW	–40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1						

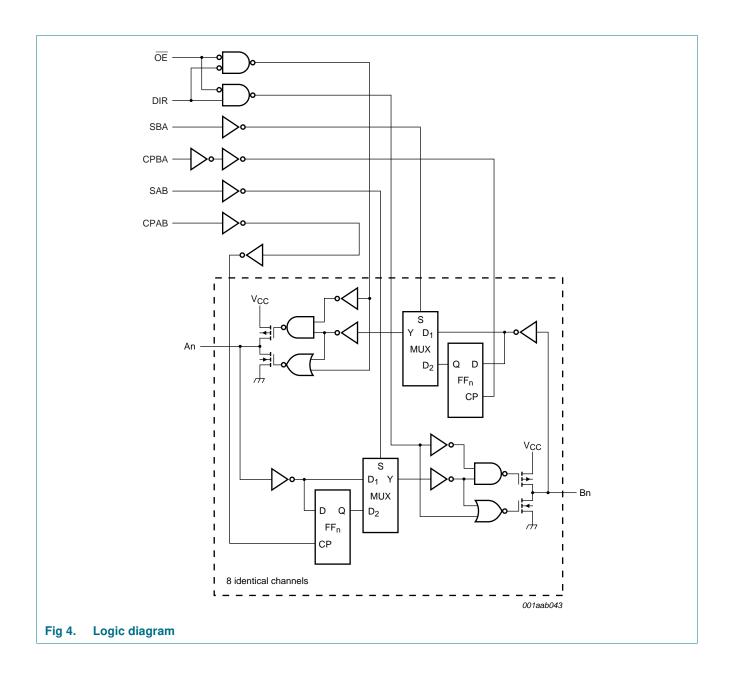
# 4. Functional diagram



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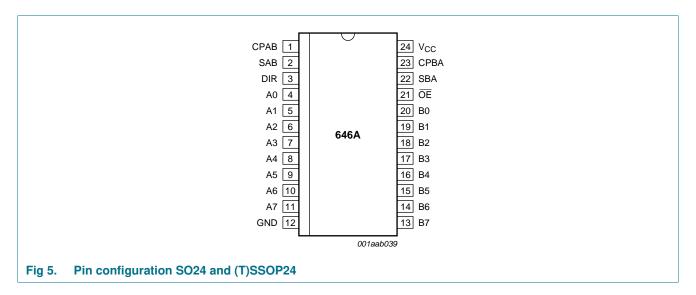
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# 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

	•	
Symbol	Pin	Description
CPAB	1	A to B clock input (LOW to HIGH; edge-triggered)
SAB	2	A to B select source input
SBA	22	B to A select source input
DIR	3	direction control input
A[0:7]	4, 5, 6, 7, 8, 9, 10, 11	A data input/output
B[0:7]	20, 19, 18, 17, 16, 15, 14, 13	B data input/output
ŌĒ	21	output enable input (active LOW)
СРВА	23	B to A clock input (LOW to HIGH, edge-triggered)
GND	12	ground (0 V)
$V_{CC}$	24	supply voltage

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# 6. Functional description

Table 3. Function table[1]

Input	Input			Data I/O		Function		
OE	DIR	CPAB	СРВА	SAB	SBA	A0 to A7	B0 to B7	
Χ	X	$\uparrow$	X	Χ	X	input	unspecified[2]	store A and B unspecified
Χ	Χ	Χ	<b>↑</b>	Χ	Χ	unspecified[2]	input	store B and A unspecified
Н	Χ	<b>↑</b>	<b>↑</b>	Χ	Χ	input	input	store A and B data
Н	Χ	H or L	H or L	Χ	Χ	input	input	hold storage; isolation
L	L	Χ	Χ	Χ	L	output	input	real-time B data to A bus
L	L	Χ	H or L	Χ	Н	output	input	stored B data to A bus
L	Н	Χ	Χ	L	X	input	output	real-time A data to B bus
L	Н	H or L	Χ	Н	X	input	output	stored A data to B bus

<sup>[1]</sup> H = HIGH voltage level

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
V <sub>I</sub>	input voltage		<u>[1]</u> –0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V	-	±50	mA
V <sub>O</sub>	output voltage	output HIGH or LOW state	[ <u>2</u> ] –0.5	$V_{CC} + 0.5$	V
		output 3-state	[ <u>2</u> ] -0.5	+6.5	V
Io	output current	$V_O = 0 V to V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[3] _	500	mW

<sup>[1]</sup> The minimum input voltage ratings may be exceeded if the input current ratings are observed.

L = LOW voltage level

X = don't care

<sup>↑ =</sup> LOW to HIGH level transition

<sup>[2]</sup> The data output functions are enabled or disabled by various signals at the OE and DIR inputs. Data input functions are always enabled, i.e. data at the bus inputs are stored on every LOW to HIGH transition on the clock inputs.

<sup>[2]</sup> The output voltage ratings may be exceeded if the output current ratings are observed.

<sup>[3]</sup> For SO24 packages: above 70 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K. For (T)SSOP24 packages: above 60 °C the value of P<sub>tot</sub> derates linearly with 5.5 mW/K.

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# 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
VI	input voltage		0	-	5.5	V
V <sub>O</sub>	output voltage	HIGH or LOW state	0	-	$V_{CC}$	V
		3-state	0	-	5.5	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	-	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	-	10	ns/V

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	<b>-40</b>	°C to +8	35 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
$V_{IH}$	HIGH-level	V <sub>CC</sub> = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
$V_{IL}$	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.12	-	0.12	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V
	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
$V_{OH}$	V <sub>OH</sub> HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$						
		$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> – 0.2	-	-	V <sub>CC</sub> – 0.3	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	1.05	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	-	-	1.65	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	2.05	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	-	2.25	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	-	-	2.0	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	-	-	0.2	-	0.3	V
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.65	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	V
II	input leakage current	$V_{CC} = 3.6 \text{ V};$ $V_{I} = 5.5 \text{ V or GND}$	-	±0.1	±5	-	±20	μА

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 Table 6.
 Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +85	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
l <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 3.6 \text{ V};$ [2] $V_{O} = 5.5 \text{ V or GND};$	-	0.1	±10	-	±20	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	-	0.1	±10	-	±20	μА
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND; $I_{O}$ = 0 A	-	0.1	10	-	40	μА
$\Delta I_{CC}$	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}$	-	5	500	-	5000	μА
C <sub>I</sub>	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_I = \text{GND to } V_{CC}$	-	5.0	-	-	-	pF
C <sub>I/O</sub>	input/output capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_{I} = \text{GND to } V_{CC}$	-	10.0	-	-	-	pF

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V (unless stated otherwise) and  $T_{amb}$  = 25 °C.

# 10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C to	+85 °C	-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation delay	An, Bn to Bn, An; see Figure 6	[2]						
		$V_{CC} = 1.2 \text{ V}$		-	17	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.8	6.9	15.8	1.8	18.2	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	3.7	8.2	1.5	9.4	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	3.6	7.8	1.5	10.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.1	6.8	1.0	8.0	ns
		CPAB, CPBA to Bn, An; see Figure 7	[2]						
		$V_{CC} = 1.2 \text{ V}$		-	19	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.4	8.6	17.8	2.4	20.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	4.5	9.1	1.7	10.5	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	4.1	8.6	1.5	11.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.8	7.6	1.0	9.5	ns
		SAB, SBA to Bn, An; see Figure 8	[2]						
		$V_{CC} = 1.2 \text{ V}$		-	19	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.5	7.6	19.8	1.5	22.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	4.0	10.2	1.5	11.8	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	4.0	9.5	1.5	12.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.4	8.5	1.0	11.0	ns

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<sup>[2]</sup> For transceivers, the parameter  $I_{\text{OZ}}$  includes the input leakage current.

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Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C to	+85 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>en</sub>	enable time	OE to An and Bn; see Figure 9	[2]						
		V <sub>CC</sub> = 1.2 V		-	20	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.4	7.2	17.8	2.4	20.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	4.1	9.8	2.0	11.3	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	4.2	8.8	1.5	11.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.0	3.3	7.8	1.0	10.0	ns
		DIR to An and Bn; see Figure 10	[2]						
		V <sub>CC</sub> = 1.2 V		-	20	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.9	8.0	18.1	2.9	20.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.4	4.5	9.9	2.4	11.5	ns
		V <sub>CC</sub> = 2.7 V		1.5	4.2	8.9	1.5	11.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.0	3.6	7.9	1.0	10.0	ns
t <sub>dis</sub>	disable time	OE to An and Bn; see Figure 9	[2]						
		V <sub>CC</sub> = 1.2 V		-	10	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		3.6	5.0	10.4	3.6	12.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	2.8	5.9	1.0	6.8	ns
		V <sub>CC</sub> = 2.7 V		1.5	3.6	7.1	1.5	9.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.3	6.1	1.0	8.0	ns
		DIR to An and Bn; see Figure 10	[2]						
		V <sub>CC</sub> = 1.2 V		-	10	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.9	3.9	10.1	2.9	11.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	2.1	5.7	1.0	6.6	ns
		V <sub>CC</sub> = 2.7 V		1.5	3.5	7.0	1.5	9.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	2.8	6.0	1.0	7.5	ns
t <sub>W</sub>	pulse width	clock HIGH or LOW of CPAB or CPBA; see Figure 7							
		V <sub>CC</sub> = 1.65 V to 1.95 V		5.0	-	-	5.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		4.0	-	-	4.0	-	ns
		$V_{CC} = 2.7 \text{ V}$		3.3	-	-	3.3	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		3.3	1.9	-	3.3	-	ns
su	set-up time	An, Bn to CPAB, CPBA; see Figure 7							
		V <sub>CC</sub> = 1.65 V to 1.95 V		3.5	-	-	3.5	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	-	-	2.5	-	ns
		$V_{CC} = 2.7 \text{ V}$		1.6	-	-	1.6	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	0.35	-	1.5	-	ns

#### Octal bus transceiver/register; 3-state

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C to	+85 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>h</sub>	hold time	An, Bn to CPAB, CPBA; see Figure 7							
		V <sub>CC</sub> = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	-	-	2.0	-	ns
		$V_{CC} = 2.7 \text{ V}$		1.0	-	-	1.0	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	-0.3	-	1.0	-	ns
f <sub>max</sub>	maximum	see Figure 7							
	frequency	V <sub>CC</sub> = 1.65 V to 1.95 V		100	-	-	80	-	MHz
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		125	-	-	100	-	MHz
		$V_{CC} = 2.7 \text{ V}$		150	-	-	120	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		150	250	-	120	-	MHz
t <sub>sk(o)</sub>	output skew time	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	-	1.0	-	1.5	ns
$C_{PD}$	power	per input; $V_I = GND$ to $V_{CC}$	<u>[4]</u>						
	dissipation	V <sub>CC</sub> = 1.65 V to 1.95 V		-	8.0	-	-	-	pF
	capacitance	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	11.7	-	-	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	15.0	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb} = 25$  °C and  $V_{CC} = 1.2$  V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

- $\begin{array}{ll} [2] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}. \\ & t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}. \\ & t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}. \end{array}$
- [3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz; f<sub>o</sub> = output frequency in MHz

 $C_L$  = output load capacitance in pF

V<sub>CC</sub> = supply voltage in Volts

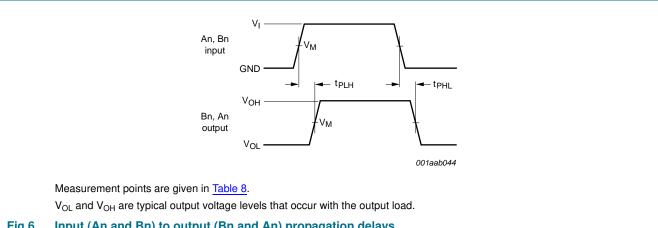
N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs

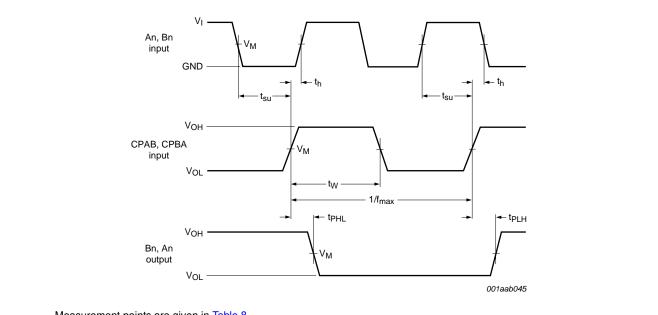
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Octal bus transceiver/register; 3-state

## 11. Waveforms



Input (An and Bn) to output (Bn and An) propagation delays Fig 6.

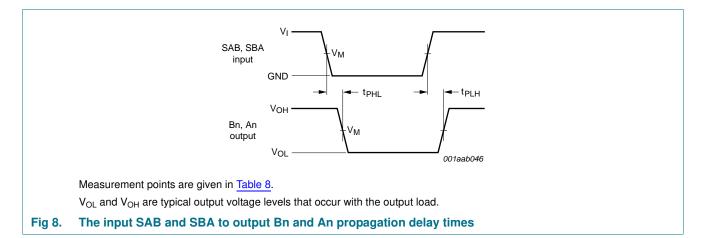


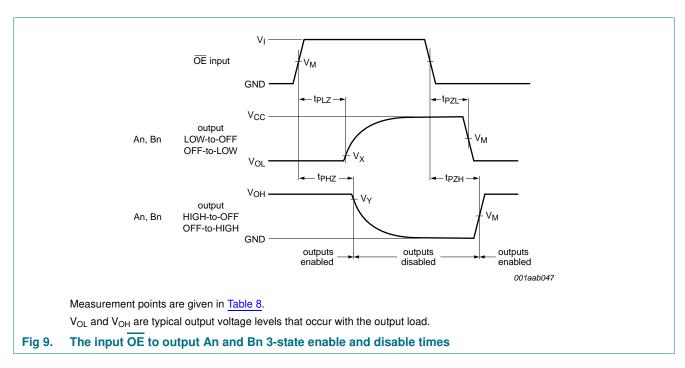
Measurement points are given in Table 8.

 $\ensuremath{V_{\text{OL}}}$  and  $\ensuremath{V_{\text{OH}}}$  are typical output voltage levels that occur with the output load.

The An, Bn to CPAB, CPBA set-up and hold times, clock CPAB and CPBA pulse width, maximum Fig 7. frequency, and the CPAB, CPBA to output Bn, An propagation delays

## Octal bus transceiver/register; 3-state





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## Octal bus transceiver/register; 3-state

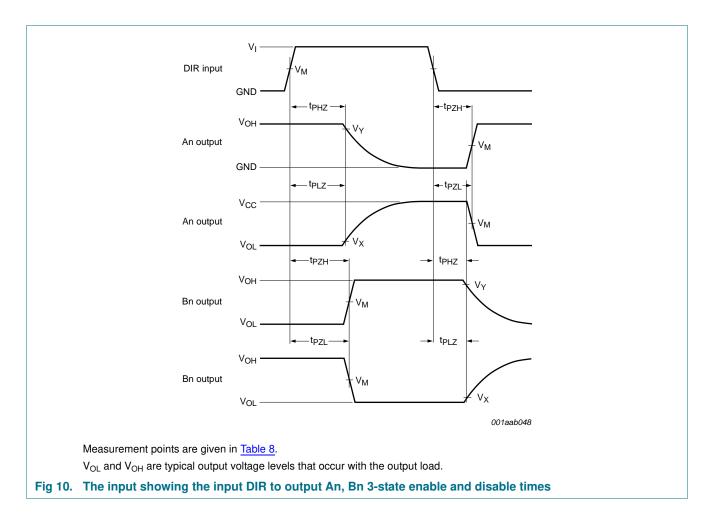
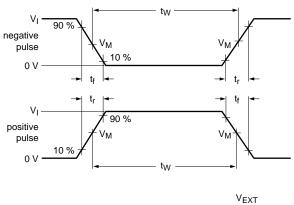
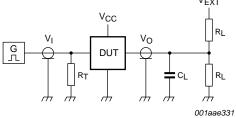


Table 8. Measurement points

Supply voltage	Input		Output	Output					
V <sub>CC</sub>	VI	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>				
1.2 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{\text{CC}}$	V <sub>OL</sub> + 0.15 V	$V_{OH}-0.15\ V$				
1.65 V to 1.95 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{\text{CC}}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V				
2.3 V to 2.7 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{\text{CC}}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V				
2.7 V	2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$				
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH}-0.3\ V$				

## Octal bus transceiver/register; 3-state





Test data is given in Table 9.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 11. Load circuitry for switching times

Table 9. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>	V <sub>EXT</sub>			
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PLZ}$ , $t_{PZL}$	t <sub>PHZ</sub> , t <sub>PZH</sub>		
1.2 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND		
1.65 V to 1.95 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND		
2.3 V to 2.7 V	$V_{CC}$	≤ 2 ns	30 pF	$500 \Omega$	open	$2\times V_{CC}$	GND		
2.7 V	2.7 V	≤ 2.5 ns	50 pF	$500~\Omega$	open	$2\times V_{CC}$	GND		
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	$500~\Omega$	open	$2\times V_{CC}$	GND		

Octal bus transceiver/register; 3-state

# 12. Application information

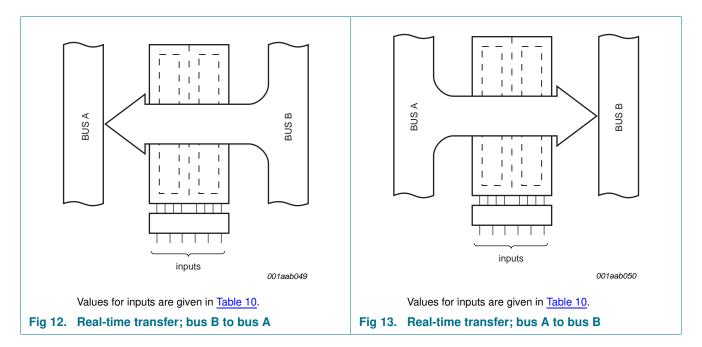


Table 10. Real-time transfer[1]

Direction	Input					
	OE	DIR	СРАВ	СРВА	SAB	SBA
Bus B to bus A	L	L	X	Χ	X	L
Bus A to bus B	L	Н	Χ	X	L	Х

<sup>[1]</sup> H = HIGH voltage level;

L = LOW voltage level;

X = don't care

## Octal bus transceiver/register; 3-state

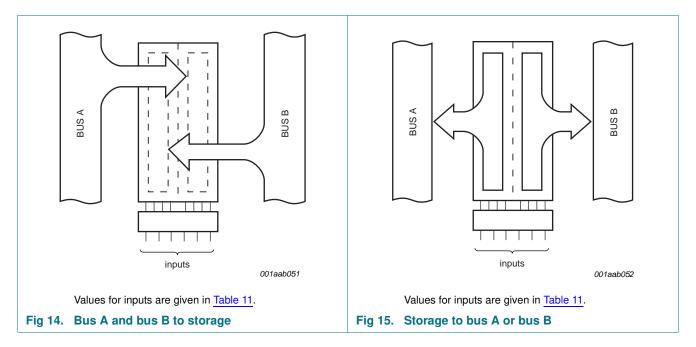


Table 11. Storage transfer[1]

Function	Input					
	OE	DIR	СРАВ	СРВА	SAB	SBA
Bus A to storage	X	Χ	<b>↑</b>	Χ	Χ	Χ
Bus B to storage	Х	Χ	X	<b>↑</b>	Χ	Χ
Bus A and B to storage	Н	Χ	<b>↑</b>	<b>↑</b>	Χ	Χ
Storage to bus A	L	L	Χ	H or L	Χ	Н
Storage to bus B	L	Н	H or L	X	Н	X

[1] H = HIGH voltage level

L = LOW voltage level

X = don't care

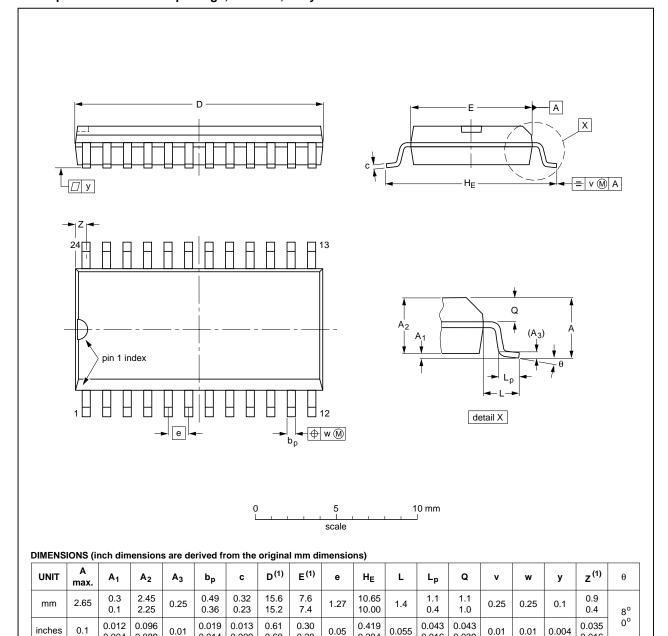
 $\uparrow$  = LOW to HIGH level transition

Octal bus transceiver/register; 3-state

## 13. Package outline

#### SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



# inches

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014

0.009

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT137-1	075E05	MS-013				<del>99-12-27</del> 03-02-19

0.394

0.016

0.039

Fig 16. Package outline SOT137-1 (SO24)

0.089

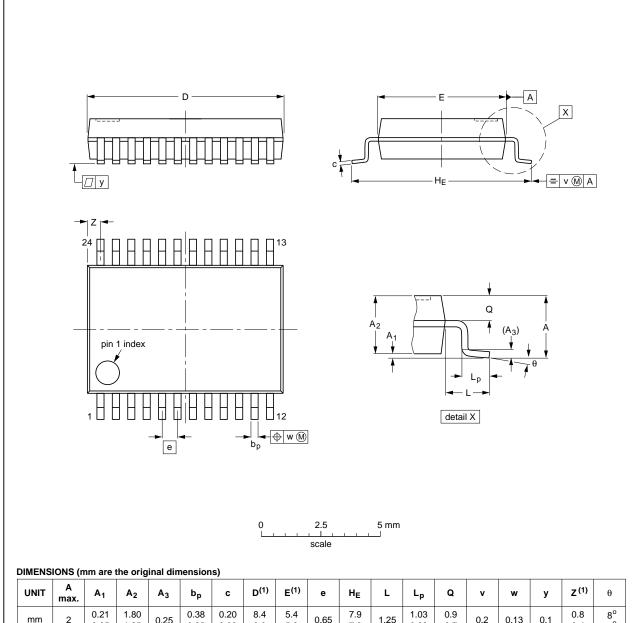
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SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	e	HE	L	Lp	ø	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

#### Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

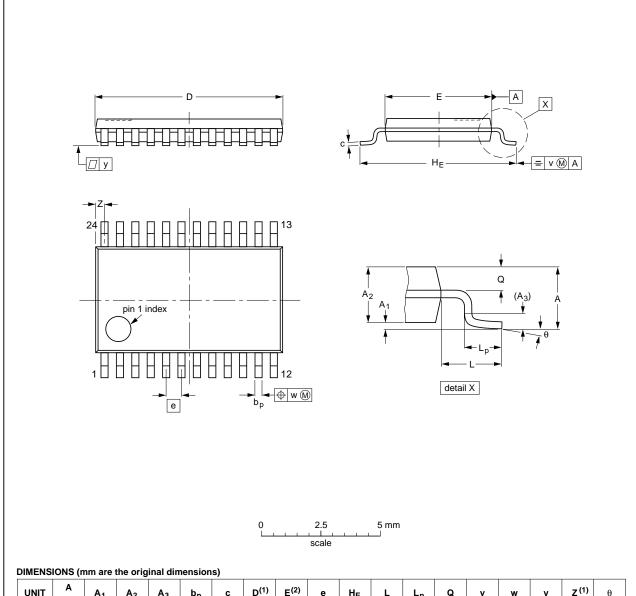
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT340-1		MO-150			<del>99-12-27</del> 03-02-19	

Fig 17. Package outline SOT340-1 (SSOP24)

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#### TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



Dimiciac	1) 01101	iiiii aic	uic orig	illai alli	101131011	3)												
UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION 99-12-27	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
SO(355-1)   MO-153   ++ H+H	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
03-02-19	SOT355-1		MO-153				<del>99-12-27</del> 03-02-19

Fig 18. Package outline SOT355-1 (TSSOP24)

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Octal bus transceiver/register; 3-state

## 14. Abbreviations

#### Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic
MM	Machine Model

# 15. Revision history

## Table 13. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC646A v.5	20130328	Product data sheet	-	74LVC646A v.4
Modifications:	<ul> <li>The format of of NXP Semice</li> </ul>	this data sheet has been reconductors.	lesigned to comply with	the new identity guidelines
	<ul> <li>Legal texts ha</li> </ul>	ve been adapted to the new	company name where	appropriate.
	• Table 4, Table	5, Table 6, Table 7, Table 8	and <u>Table 9</u> : values add	led for lower voltage ranges.
74LVC646A v.4	20040629	Product specification	-	74LVC646A v.3
74LVC646A v.3	20000621	Product specification	-	74LVC646A v.2
74LVC646A v.2	19980729	Product specification	-	74LVC646A v.1
74LVC646A v.1	19980325	Product specification	-	-

#### Octal bus transceiver/register; 3-state

## 16. Legal information

#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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#### Octal bus transceiver/register; 3-state

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## Octal bus transceiver/register; 3-state

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